Subst. Form PTO-1449 Atty. Dock t N .: 122370/RD30124 Serial No.: To be assigned GLOZ 2 00135 APPLICANT'S(S') INFORMATION Applicant(s): Anant Achyut Setlur, et al. **DISCLOSURE STATEMENT** Group: Unknown Filing Dat: Herewith **U.S. PATENT DOCUMENTS** Document No. Date. Class Subcl. Filing Date Initial* Name 5,851,063 12/22/1998 AA Doughty et al. 12/07/1999 5,998,925 AΒ Shimizu et al. AC 01/11/2000 McFarland et al. 6,013,199 05/23/2000 6,066,861 AD Höhn et al. ΑE 6,069,440 05/30/2000 Shimizu et al. 07/04/2000 ÁF 6,084,250 Jüstel et al. AG 6,096,243 08/01/2000 Oshio et al. 6,203,726 03/20/2001 AH Danielson et al. 04/03/2001 AI 6,210,605 Srivastava et al. 06/26/2001 AJ 6,252,254 Soules et al. AK 6,255,670 07/03/2001 Srivastava et al. 08/21/2001 ΑL 6,278,135 Srivastava et al. 'nν AM 6,294,800 09/25/2001 Duggal,et al. AN 6,351,069 02/26/2002 Lowery et al. 04/02/2002 AO 6,366,033 Greci et al. AΡ 6,402,987 06/11/2002 Srivastava et al. ΑQ 6,504,179 01/07/2003 Ellens et al. AR 6,513,949 02/04/2003 Marshall et al. AS 6,515,314 02/04/2003 Duggal et al. FOREIGN PATENT DOCUMENTS Document No. Date Country Class Subcl. Translation? ΑT OTHER ART ΑU ummerman Examiner: Date Considered: EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if in conformance and no considered. Include copy of this form with next communication to applicant.

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